

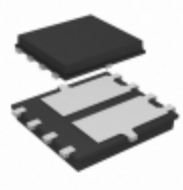

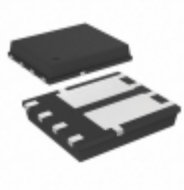
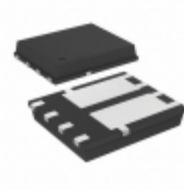



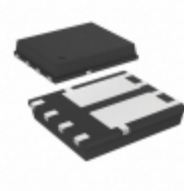
	<h2 style="color: #D9534F;">SI7940DP-T1-E3</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: SI7940DP-T1-E3
	Hersteller / Marke: Electro-Films (EFI) / Vishay
	Teil der Beschreibung: MOSFET 2N-CH 12V 7.6A PPAK SO-8
	Datenblätter:  SI7940DP-T1-E3.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 1692 pcs Stock Available.
	Liefern von: Hong Kong
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	SI7940DP-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET 2N-CH 12V 7.6A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	1692 pcs Stock
detaillierte Beschreibung	Mosfet Array 2 N-Channel (Dual) 12V 7.6A 1.4W
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.4W
Verpackung / Gehäuse	PowerPAK® SO-8 Dual
Supplier Device-Gehäuse	PowerPAK® SO-8 Dual
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	12V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	7.6A
Rds On (Max) @ Id, Vgs	17 mOhm @ 11.8A, 4.5V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	17nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)
Basisteilenummer	SI7940
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)








































SI7940DP-T1-E3 ist neu im Original, Suche SI7940DP-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7940DP-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI7940DP-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7925DN-T1-GE3 Vishay / Siliconix MOSFET 2P-CH 12V 4.8A 1212-8</p>	 <p>SI7940DP VISHAY SI7940DP VISHAY</p>	 <p>SI7938DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 40V 60A PPAK SO-8</p>	 <p>SI7940DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 12V 7.6A PPAK SO-8</p>
 <p>SI7940DP-T1-E3 Vishay / Siliconix MOSFET 2N-CH 12V 7.6A PPAK SO-8</p>	 <p>SI7938DP-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 40V 60A PPAK SO-8</p>	 <p>SI7941DP VISHAY SI7941DP VISHAY</p>	 <p>SI7940DP-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 12V 7.6A PPAK SO-8</p>

heiße Teile

Mehr

 SI7905DN-T1-GE3	 SI7909DN-T1-E3	 SI7909DN-T1-E3	 SI7909DN-T1-GE3	 SI7909DN-T1-GE3
 SI7911DN	 SI7911DN-T1-E3	 SI7911DN-T1-E3	 SI7911DN-T1-GE3	 SI7911DN-T1-GE3
 SI7913DN-T1-E3	 SI7913DN-T1-E3	 SI7913DN-T1-GE3	 SI7913DN-T1-GE3	 SI7922DN-T1-E3
 SI7922DN-T1-E3	 SI7922DN-T1-GE3	 SI7922DN-T1-GE3	 SI7923DN-T1-E3	 SI7923DN-T1-E3
 SI7923DN-T1-GE3	 SI7923DN-T1-GE3	 SI7938DP-T1-GE3	 SI7938DP-T1-GE3	 SI7940DP
 SI7940DP-T1-E3	 SI7941DP-T1-E3	 SI7941DP-T1-GE3	 SI7942DP	 SI7942DP-T1-E3
 SI7942DP-T1-E3	 SI7942DP-T1-GE3	 SI7942DP-T1-GE3	 SI7945DP-T1-E3	 SI7945DP-T1-E3
 SI7946DP	 SI7946DP-T1-E3	 SI7946DP-T1-E3	 SI7948DP	 SI7948DP-T1-E3
 SI7949DP-T1-GE3	 SI7949DP-T1-GE3	 SI7956DP-T1-GE3	 SI7956DP-T1-GE3	 SI7958DP
 SI7958DP-T1-E3	 SI7958DP-T1-E3	 SI7958DP-T1-GE3	 SI7958DP-T1-GE3	 SI7960DP-T1-E3

Contact us:Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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